

Product Overview

MSA1162: PNP Bipolar Transistor

For complete documentation, see the data sheet.

The PNP Bipolar Transistor is designed for use in linear and switching applications. The device is housed in the SC-59 package, which is designed for lower power surface mount applications.

Features

- Moisture Sensitivity Level: 1
- Pb-Free Packages are Available

Part Electrical Specifications

Product	Compliance	Status	Polarity	Type	$V_{CE(sat)}$ Max (V)	I_C Cont. (A)	V_{CE0} Min (V)	V_{CBO} (V)	V_{EBO} (V)	$V_{BE(sat)}$ (V)	$V_{BE(on)}$ (V)	h_{FE} Min	h_{FE} Max	f_T Min (MHz)	P_{TM} Max (W)	Package Type
MSA1162GT1G	Pb-free	Active	PNP	General Purp ose	0.5	0.1	50	60	7	-	-	200	400	80	0.2	SC- 59-3
	Halide free															
NSVMSA1162GT1G	AEC Qualified PPAP Capable Pb-free Halide free	Active	PNP	General Purp ose	0.5	0.1	50	60	7	-	-	120	240	80	0.2	SC- 59-3

For more information please contact your local sales support at www.onsemi.com.

Created on: 11/12/2018